2018년 2월 7일(수), 10:45-12:15 Room D (함백II+III, 5층)

E. Compound Semiconductors 분과 [WD2-E] III-V Emerging Device

	InGaAs QW MOSFETs with Record $\mu n_{eff} = 6,980 \text{ cm}^2/\text{V-s}$: from Fabrication
WD2-E-1 10:45-11:00	to BTI Characteristics. Seung-Woo Son ^{1,2} , Hyuk-Min Kwon ³ , Jung Ho Park ¹ , Ji-Min Baek ¹ , Hyeon-Bhin Cho ¹ , Yong Hyun Seo ³ , Min Yung Lee ³ , Dong-Hyun Kim ² , Chan-Soo Shin ² , and
	Dae-Hyun Kim ¹ ¹ School of Electronics Engineering, Kyungpook National University, ² Korea Advanced Nanofab Center, ³ SK-Hynix
WD2-E-2 11:00-11:15	Avalanche Photodiodes for Hazardous Airborne Particle Monitoring System Eugene Chong ¹ , Byeong Hwang Park ¹ , Ho-Young Cha ² , Kyeong-Keun Choi ³ , Young-Su Jeong ¹ , Hong-Kyu Lee ¹ , Young-Jin Ko ¹ , Jong-Seon Kim ¹ , Hyun-Woo Nam ¹ , Hyun-Jung Kim ¹ , Juno Lee ¹ , Jae- Hwan Lee ¹ , Jeong Yoon Lee ³ , and Min Jae Kang ³ 1 CB Detection Team, ADD, 2 Hongik University, 3 NINT, POSTECH
WD2-E-3 11:15-11:30	Impact of Ground Plane Doping on InGaAs-OI MOSFETs Seong Kwang Kim ^{1,2} , Jae-Phil Shim ¹ , Dae-Myeong Geum ^{1,3} , Jaewon Kim, Chang Zoo Kim ⁴ , Han-Sung Kim ¹ , Jin-Dong Song ¹ , Sung-Jin Choi ² , Dae Hwan Kim ² , Won Jun Choi ¹ , Hyung-jun Kim ¹ , Dong Myong Kim ² , and Sanghyeon Kim ¹ **IKIST, **School of Electrical Engineering, Kookmin University, **Department of Materials Science and Engineering, Seoul National University, *KANC**
WD2-E-4 11:30-11:45	Enhanced UV Absorption of Photodiode with ZnO Quantum Dot Antireflection Coating Layer Jong-Ik Kang ¹ , Chang-Yeol Han ² , Heesun Yang ² , Seong Ran Jeon ³ , Eugene Chong ⁴ , Byeonghwang Park ⁴ , Young Il Kang ⁴ , and Ho-Young Cha ¹ 1 School of Electronic and Electrical Engineering, Hongik University, 2 Department of Materials Science and Engineering, Hongik University, 3 KOPTI, 4 Chem-Bio Division, Agency for Defense Development
WD2-E-5 11:45-12:15	[초청] Ultra Wide Bandgap Ga ₂ O ₃ Materials for Next Generation Power Electronics Applications Youngboo Moon ¹ , Hyun Yeop Lee ¹ , Hyung Seok Jung ¹ , Daejang Lee ² , and Jun-Seok Ha ² ¹ UJL, ² School of Applied Chemical Engineering, Chonnam National University